



PTO/SB/085 (08-03)

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Subpoena Form 1449APTO

## **INFORMATION DISCLOSURE STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

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**Complete if Known**

Application Number	09/787,189
Filing Date	March 15, 2001
First Named Inventor	David B. Slater, Jr.
Art Unit	2818
Examiner Name	David Vu
Attorney Docket Number	5000.113

**U. S. PATENT DOCUMENTS**

## FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No.*	Foreign Patent Document	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T
		Country Code <sup>1</sup> Number <sup>2</sup> Kind Code <sup>3</sup> (if known)	MM-DD-YYYY			
DV	2	PCT WO 00/18382 A1	03-23-2000	Cree Research, Inc.		
DV	3	EP 0 789 388 A2	08-13-1997	Agency Ind Sci Techn		

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Signature

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**Date  
Considered**

10/27/04

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Substitute for form 1449B/PTO				Complete if Known	
				Application Number	09/787,189
				Filing Date	March 15, 2001
				First Named Inventor	David B. Slater, Jr.
				Art Unit	2818
				Examiner Name	David Vu
(Use as many sheets as necessary)					
Sheet	2	of	2	Attorney Docket Number	5000.113

## NON-PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
DV	4	A. MOKI et al.; "Low Resistivity As-Deposited Ohmic Contacts to 3C-SiC"; Journal of Electronic Materials; 1995; pages 315-318; Vol. 24, No. 4	
PV	5	T. TADAO et al.; "Lowering the Annealing Temperature of Ni/SiC for Ohmic Contacts under N(2) Gas, and Application to a UV Sensor"; Materials Science Forum; pgs 989-992; Vols. 338-342 (2000)	

Examiner Signature	Shuland	Date Considered:	10/27/04
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